

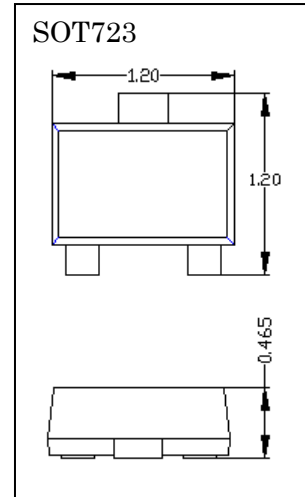
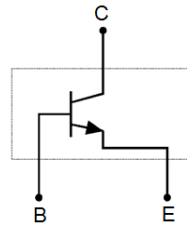
DATA SHEET

MMBT3904M

- ◇ Capable of 200 mWatts of Power Dissipation and 200mA Ic
- ◇ Operating and Storage Junction Temperatures: -55°C to 150°C
- ◇ Small Outline Surface Mount Package
- ◇ RoHS compliant / Green EMC

Device Marking Code	
MMBT3904	1N

Circuit Diagram



MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CB0}	Collector-Base Voltage	60	V
V _{CE0}	Collector-Emitter Voltage	40	V
V _{EB0}	Emitter-Base Voltage	6	V
I _c	Collector Current	200	mA
P _c	Collector Power Dissipation	100	mW
R _{θJA}	Thermal Resistance From Junction To Ambient	1250	°C/W
T _j	Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55~+150	°C

ELECTRICAL CHARACTERISTICS @ 25° C Unless Otherwise Specified

Symbol	Parameter	Test Conditions	Min	Max	Units
V _{CE0}	Collector-Emitter Breakdown Voltage	I _c =1.0mA, I _B =0	40		V
V _{CB0}	Collector-Base Breakdown Voltage	I _c =10μA, I _E =0	60		V
V _{EB0}	Emitter-Base Breakdown Voltage	I _E =10μA, I _c =0	6		V

I_{CBO}	Collector Cutoff Current	$V_{CB}=30V, I_E=0$		100	nA
I_{CEX}	Collector Cutoff Current	$V_{CE}=30V, V_{EB(OFF)}=3.0V$		50	nA
I_{EBO}	Collector Cutoff Current	$V_{EB}=5V, I_C=0$		100	nA
$h_{FE(1)}$	DC Current Gain	$I_C=0.1mA, V_{CE}=1V$	40		
$h_{FE(2)}$	DC Current Gain	$I_C=1mA, V_{CE}=1V$	70		
$h_{FE(3)}$	DC Current Gain	$I_C=10mA, V_{CE}=1V$	100	300	
$h_{FE(4)}$	DC Current Gain	$I_C=50mA, V_{CE}=1V$	60		
$V_{CE(sat)1}$	Collector-Emitter Saturation Voltage	$I_C=10mA, I_B=1mA$		0.2	V
$V_{CE(sat)2}$	Collector-Emitter Saturation Voltage	$I_C=50mA, I_B=5mA$		0.3	V
$V_{BE(sat)1}$	Base-Emitter Saturation Voltage	$I_C=10mA, I_B=1mA$	0.65	0.85	V
$V_{BE(sat)2}$	Base-Emitter Saturation Voltage	$I_C=50mA, I_B=5.0mA$		0.95	V
f_T	Current Gain-Bandwidth Product	$I_C=10mA, V_{CE}=20V, f=100MHz$	300		MHz

SWITCHING CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min	Max	Units
t_d	Delay Time	$V_{CC}=3.0V, V_{BE(off)}=-0.5V$		35	ns
t_r	Rise Time	$I_C=10mA, I_{B1}=1.0mA$		35	ns
t_s	Storage Time	$V_{CC}=3.0V, I_C=10mA$		200	ns
t_f	Fall Time	$I_{B1}=I_{B2}=1.0mA$		50	ns

ORDERING INFORMATION

Device	Package	Shipping	Tape wide	Emboss pitch	Tape specification	Notes
MMBT3904M	SOT723	Tape & Reel 8000pcs /7" Reel	8mm	4mm	Conductive	

PACKAGE DIMENSIONS

Package outline : SOT723

Top view

Side view

SYMBOL	DIMENSIONS IN MILLIMETER	
	MIN	MAX
A	0.430	0.500
A1	0.000	0.050
b	0.170	0.270
b1	0.270	0.370
c	0.080	0.150
D	1.150	1.250
E	1.150	1.250
E1	0.750	0.850
e	0.800 TYP.	
θ	0°	7°

Front view

Soldering Pattern

Notice:

1. Lead plating: Pb free solder
2. Lead thickness includes solder plating
3. Lead frame: CAC-5
4. Other Tolerance: ±0.05
5. Dimensions are exclusive of Burrs, Mold Flash and Tie Bar extrusions
6. Unit: mm